*Anloy Technologies*

*256 x 4bit Fully Decoded SRAM*

# *AT93L422*

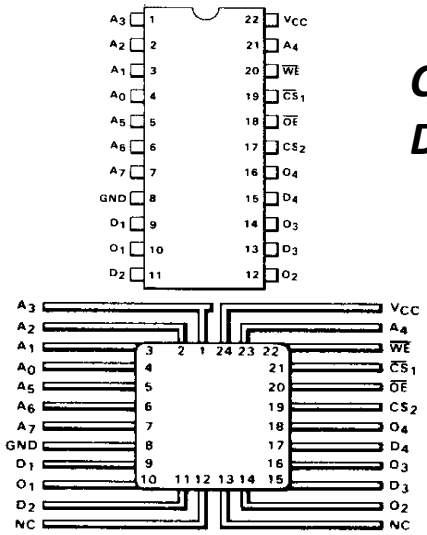
## Die Manufacturers Available

» **National Semiconductor**

## Product Features

**» Operating Temperature range of +125°C to -55°C**
**» Isoplanar Technology**
**» 3 - State Output**
**» Two Chip Select Inputs for Easy Expansion**
**» Low Power Dissipation - 0.27 mW/Bit Typical**
**» Typical Read Access Time - 45ns**

## Device Pin Outs




***Ceramic Dip***
***D Suffix***

***Flat Pack***
***(Top View)***
***F Suffix***

**The die can be packaged in other footprints, contact Anloy for further details.**

## General Description

**The 93L422 is a 1024-bit Read/Write Random Access Memory organized as 256 words by four bits per word. The 93L422 has 3-state outputs, and is designed primarily for buffer control storage and high performance main memory applications. For further electrical specifications please contact Anloy Technologies or reference the original die manufacturers datasheet.**

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